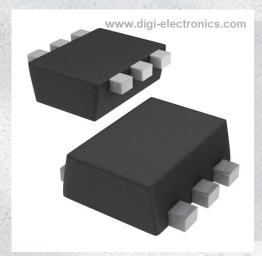


PEMD4,115 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number PEMD4,115-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PEMD4,115

Description TRANS PREBIAS 1NPN 1PNP SOT666

Detailed Description Pre-Biased Bipolar Transistor (BJT) 1 NPN, 1 PNP - P re-Biased (Dual) 50V 100mA 300mW Surface Moun

t SOT-666



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PEMD4,115	Nexperia USA Inc.
Series:	Product Status:
	Not For New Designs
Transistor Type:	Current - Collector (Ic) (Max):
1 NPN, 1 PNP - Pre-Biased (Dual)	100mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50V	10kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ Ic, Vce:
	200 @ 1mA, 5V
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
150mV @ 500μA, 10mA	1μΑ
Frequency - Transition:	Power - Max:
	300mW
Mounting Type:	Package / Case:
Surface Mount	SOT-563, SOT-666
Supplier Device Package:	Base Product Number:
SOT-666	PEMD4

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



PEMD4

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

28 December 2022

Product data sheet

1. General description

NPN/PNP double Resistor-Equipped Transistor (RET) in an ultra small and flat lead SOT666 Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PEMH4 PNP/PNP complement: PEMB4

2. Features and benefits

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs

3. Applications

- Low current peripheral driver
- · Replacement for general purpose transistors in digital applications
- · Controlling IC inputs

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor;	Per transistor; for the PNP transistor with negative polarity						
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
I _O	output current			-	-	100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ

[1] See section "Test information" for resistor calculation and test conditions.



50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	6 5 4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2		R1
6	O1	output (collector) TR1	1 2 3 SOT666	GND1 I1 O2 006aaa269

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PEMD4		plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code
PEMD4	23

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

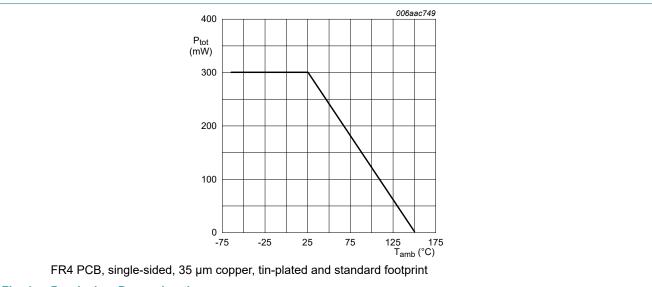
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit		
Per transistor;	Per transistor; for the PNP transistor with negative polarity							
V _{CBO}	collector-base voltage	open emitter		-	50	V		
V_{CEO}	collector-emitter voltage	open base		-	50	V		
V _{EBO}	emitter-base voltage	open collector		-	5	V		
Io	output current			-	100	mA		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	200	mW		
T _j	junction temperature			-	150	°C		
T _{amb}	ambient temperature			-65	150	°C		
T _{stg}	storage temperature			-65	150	°C		
Per device								
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	300	mW		

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.



50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or		'			_	
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	416	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.

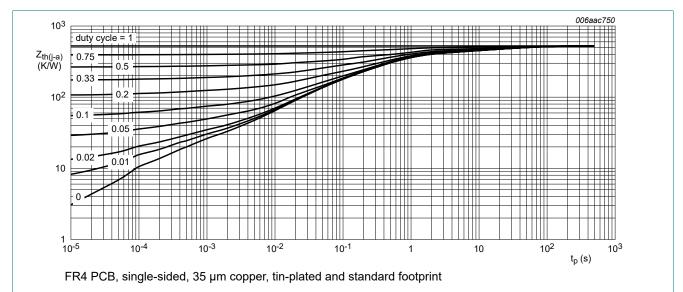


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or; for the PNP transistor	with negative polarity					
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
Ісво	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μΑ
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 1 mA; T _{amb} = 25 °C		200	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	150	mV
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
Transistor 1	TR1 (NPN)						
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
Transistor T	TR2 (PNP)		•		•		
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	3	pF

^[1] See section "Test information" for resistor calculation and test conditions.

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

11. Test information

Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_I = \frac{V(I_2) - V(I_I)}{I_2 - I_I}$$

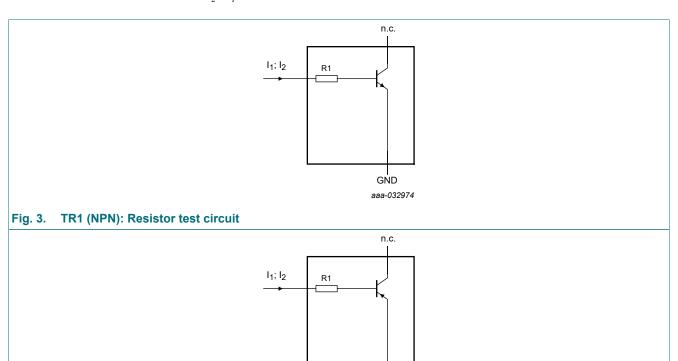


Fig. 4. TR2 (PNP): Resistor test circuit

Resistor test conditions

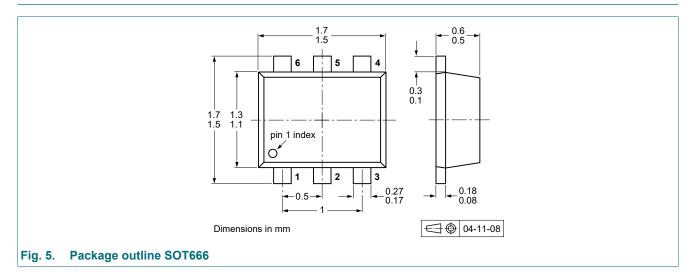
Table 8. Resistor test conditions

PEMD4	R1 (kΩ)	R2 (open)	Test conditions	
			l ₁	l ₂
TR1 (NPN)	10	-	350 μΑ	450 μΑ
TR2 (PNP)	10	-	-350 μΑ	-450 μΑ

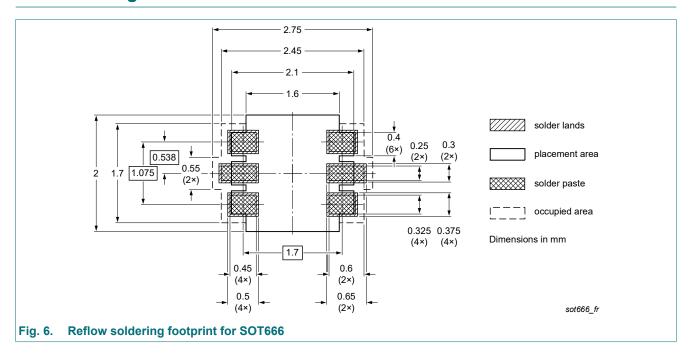
aaa-032975

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

12. Package outline



13. Soldering



50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PEMD4 v.3	20221228	Product data sheet	-	PEMD4_PUMD4 v.2	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Family data sheet reduced to single type data sheet. Product(s) changed to non-automotive qualification. 				
PEMD4_PUMD4 v.2	20031010	Product data sheet	-	PEMD4_PUMD4 v.1	
PEMD4_PUMD4 v.1	20020114	Product data sheet	-	-	

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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PEMD4

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = open

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